

Electronic Supplementary Information

Preparation of AgInS₂ quantum dots/In₂S₃ co-sensitized photoelectrodes by a facile aqueous-phase synthesis route and their photovoltaic performance

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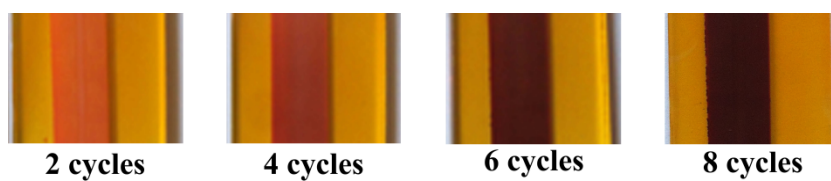


Fig. 1S Photograph images of $\text{TiO}_2/\text{AgInS}_2\text{-QDs}/\text{In}_2\text{S}_3$ electrodes obtained by CBD of In_2S_3 and *in situ* reaction with different cycle of Ag_2S SILAR deposition on TiO_2 films.

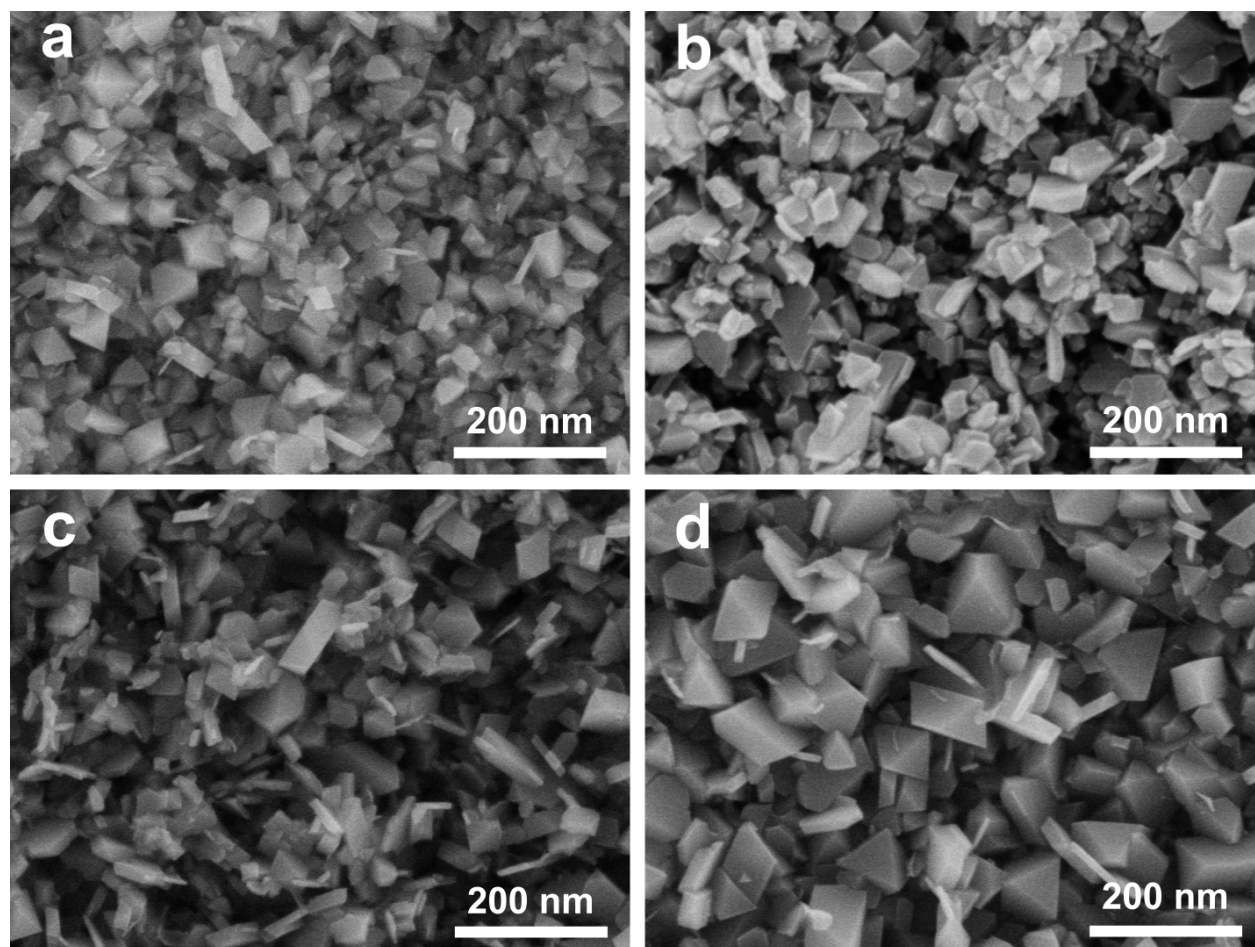


Fig. 2S FESEM images of $\text{TiO}_2/\text{AgInS}_2\text{-QDs}/\text{In}_2\text{S}_3$ photanodes obtained by CBD of In_2S_3 and *in situ* reaction with different cycle of Ag_2S SILAR deposition on TiO_2 films: (a) 2 cycles. (b) 4 cycles. (c) 6 cycles. (d) 8 cycles.

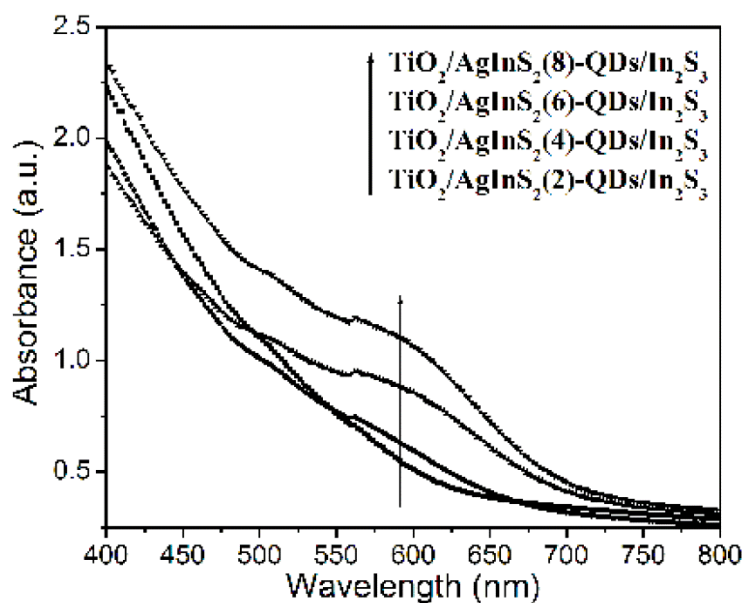


Fig. 3S Optical absorption spectra of $\text{TiO}_2/\text{AgInS}_2\text{-QDs}/\text{In}_2\text{S}_3$ photonaodes obtained by CBD of In_2S_3 and *in situ* reaction with different cycle of Ag_2S SILAR deposition on TiO_2 films.

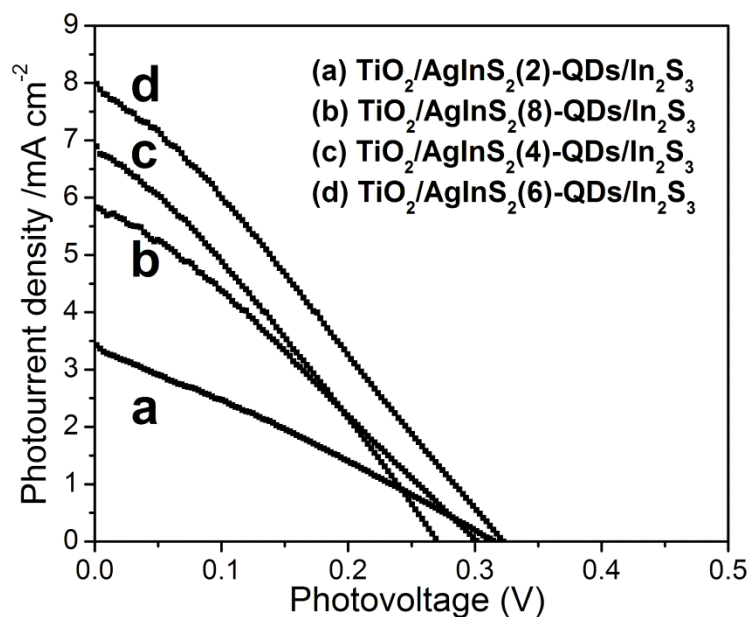


Fig. 4S Photocurrent voltage characteristics of $\text{TiO}_2/\text{AgInS}_2\text{-QDs}/\text{In}_2\text{S}_3$ photonaodes obtained by CBD of In_2S_3 and *in situ* reaction with different cycle of Ag_2S SILAR deposition on TiO_2 films.

Table 1S Photovoltaic parameters of $\text{TiO}_2/\text{AgInS}_2\text{-QDs}/\text{In}_2\text{S}_3$ photonaodes obtained by CBD of In_2S_3 and *in situ* reaction with different cycle of Ag_2S SILAR deposition on TiO_2 films.

Photoanode	J_{sc} (mA cm^{-2})	V_{oc} (V)	FF	η (%)
$\text{TiO}_2/\text{AgInS}_2(2)\text{-QDs}/\text{In}_2\text{S}_3$	3.39	0.31	0.28	0.30 ± 0.02
$\text{TiO}_2/\text{AgInS}_2(4)\text{-QDs}/\text{In}_2\text{S}_3$	6.82	0.27	0.29	0.54 ± 0.02
$\text{TiO}_2/\text{AgInS}_2(6)\text{-QDs}/\text{In}_2\text{S}_3$	7.87	0.32	0.28	0.70 ± 0.02
$\text{TiO}_2/\text{AgInS}_2(8)\text{-QDs}/\text{In}_2\text{S}_3$	5.82	0.30	0.28	0.50 ± 0.02